

1.0A SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER
POWERDI®

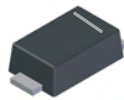
Features

- Ultra-Small Surface Mount Package
- Guard Ring Die Construction for Transient Protection
- High Surge Capability
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

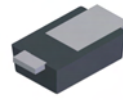
Mechanical Data

- Case: POWERDI323
- Case Material: Molded Plastic, "Green" Molding Compound.
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Polarity: Cathode Band
- Terminals: Finish - Matte Tin annealed over Copper leadframe.
Solderable per MIL-STD-202, Method 208 
- Weight: 0.006 grams (approximate)

POWERDI323



Top View



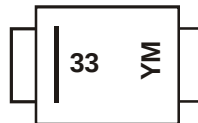
Bottom View

Ordering Information (Note 4)

Part Number	Case	Packaging
PD3S140-7	POWERDI323	3000/Tape & Reel
PD3S140Q-7	POWERDI323	3000/Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com>.

Marking Information



33 = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: U = 2006)
M = Month (ex: 9 = September)

Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016	2017	2018
Code	T	U	V	W	X	Y	Z	A	B	C	D	E	F

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.
 For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	40	V
Working Peak Reverse Voltage	V _{RWM}		
DC Blocking Voltage	V _R		
Average Forward Current (See also figure 4)	I _{F(AV)}	1.0	A
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I _{FSM}	22	A

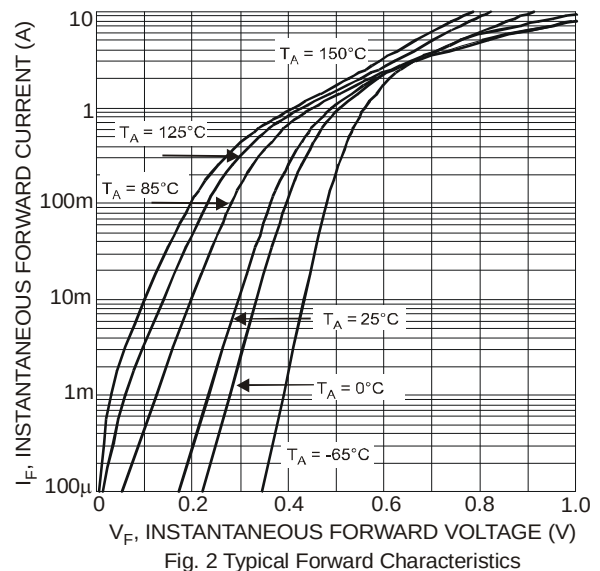
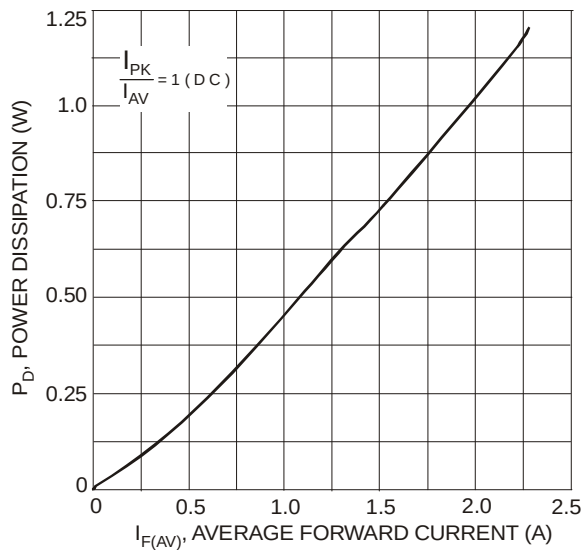
Thermal Characteristics

Characteristic	Symbol	Typ	Max	Unit
Thermal Resistance Junction to Soldering Point	R _{θJS}	—	15	°C/W
Thermal Resistance Junction to Ambient Air (Note 5)	R _{θJA}	175	—	°C/W
Thermal Resistance Junction to Ambient Air (Note 6)	R _{θJA}	130	—	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150		°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 7)	V _{(BR)R}	40	—	—	V	I _R = 100μA
Forward Voltage	V _F	—	0.37	0.42	V	I _F = 0.1A
		—	0.44	0.50		I _F = 0.5A
		—	0.46	0.52		I _F = 0.7A
		—	0.49	0.55		I _F = 1.0A
		—	0.3	4		V _R = 5V, T _A = +25°C
Leakage Current (Note 7)	I _R	—	2	50	μA	V _R = 40V, T _A = +25°C
Total Capacitance (See also figure 3)	C _T	—	32	—	pF	V _R = 10V, f = 1.0MHz

Notes: 5. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per <http://www.diodes.com>. T_A = +25°C.
 6. Polyimide PCB, 2 oz. Copper, minimum recommended pad layout per <http://www.diodes.com>. T_A = +25°C.
 7. Short duration pulse test used to minimize self-heating effect.



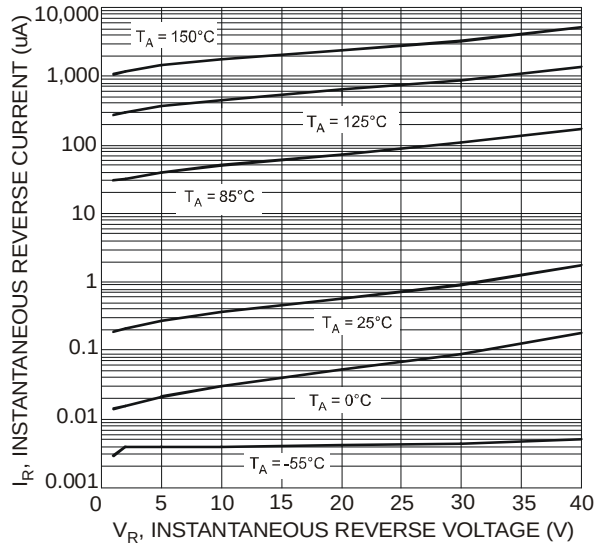


Fig. 3 Typical Reverse Characteristics

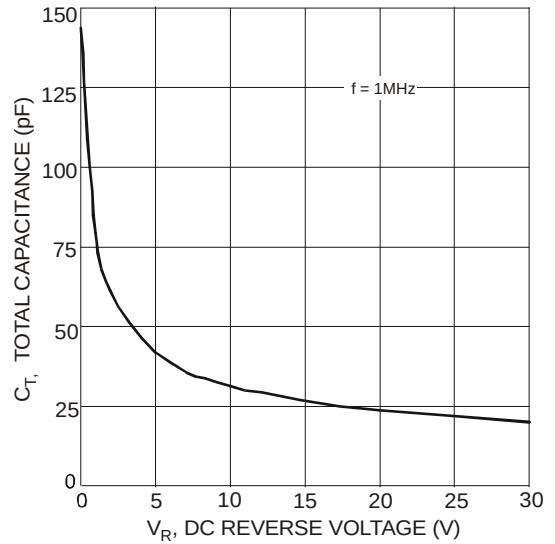


Fig. 4 Total Capacitance vs. Reverse Voltage

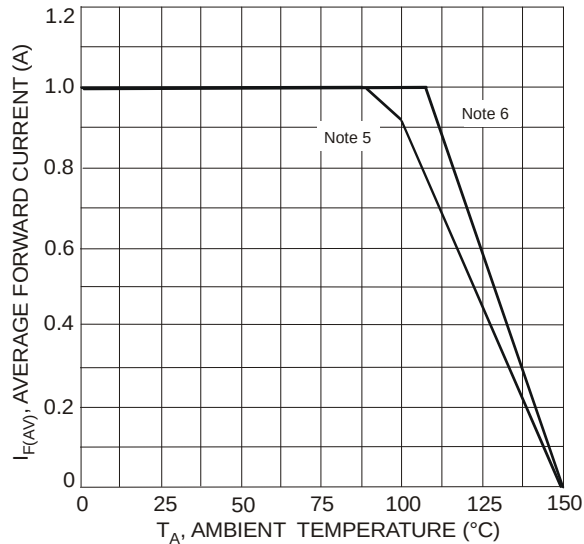


Fig. 5 Forward Current Derating Curve

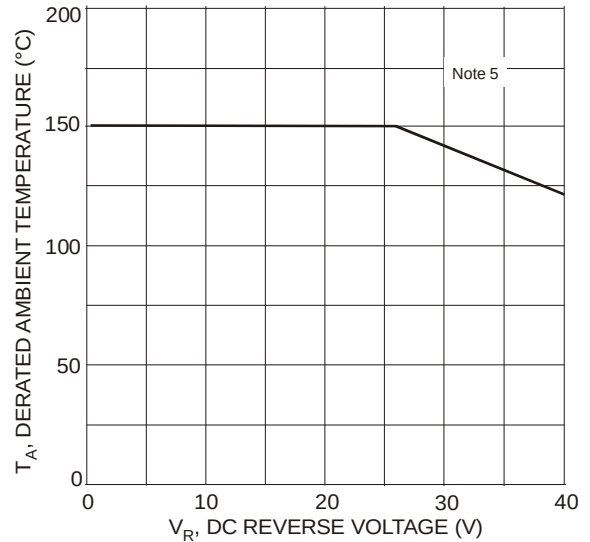
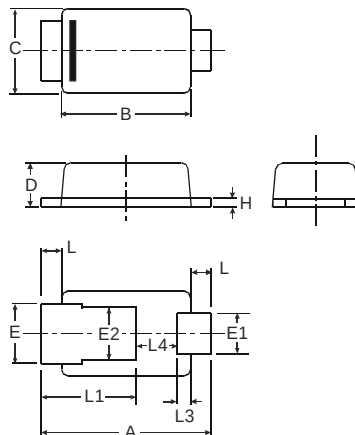


Fig. 6 Operating Temperature Derating

Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

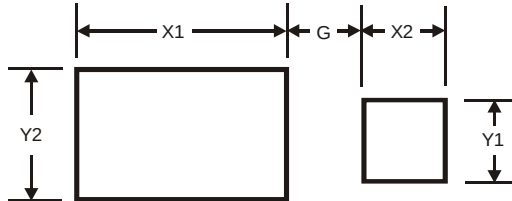


POWERDI323			
Dim	Min	Max	Typ
A	2.40	2.60	2.50
B	1.85	1.95	1.90
C	1.20	1.30	1.25
D	0.60	0.70	0.65
E	0.78	0.98	0.88
E1	0.50	0.70	0.60
E2	0.60	1.00	0.80
H	0.08	0.18	0.13
L	0.20	0.40	0.30
L1	—	—	1.40
L3	—	—	0.20
L4	0.40	0.80	0.60

All Dimensions in mm

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
G	0.5
X1	2.0
X2	0.8
Y1	0.8
Y2	1.1

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